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With the principle of "Quality Parts, Customers Priority, Honest Operation, and Considerate Service", our business mainly focus on the distribution of electronic components. Line cards we deal with include Microchip, ALPS, ROHM, Xilinx, Pulse, ON, Everlight and Freescale. Main products comprise IC, Modules, Potentiometer, IC Socket, Relay, Connector. Our parts cover such applications as commercial, industrial, and automotives areas.

We are looking forward to setting up business relationship with you and hope to provide you with the best service and solution. Let us make a better world for our industry!



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KSD1020

Audio Frequency Amplifier

Complement to KSB810



1.Emitter 2. Collector 3. Base

NPN Epitaxial Silicon Transistor

Absolute Maximum Ratings T_a =25°C unless otherwise noted

Symbol	Parameter	Ratings	Units
V _{CBO}	Collector-Base Voltage	30	V
V _{CEO}	Collector-Emitter Voltage	25	V
V _{EBO}	Emitter-Base Voltage	5.0	V
I _C	Collector Current (DC)	700	mA
I _{CP}	* Collector Current (Pulse)	1.0	Α
P _C	Collector Power Dissipation	350	mW
T _J	Junction Temperature	150	°C
T _{STG}	Storage Temperature	-55 ~ 150	°C

^{*} PW≤10ms, Duty Cycle≤50%

Electrical Characteristics T_a=25°C unless otherwise noted

Symbol	Parameter	Test Condition	Min.	Тур.	Max.	Units
I _{CBO}	Collector Cut-off Current	V_{CB} =30V, I_{E} =0			100	nA
I _{EBO}	Emitter Cut-off Current	$V_{EB}=5V$, $I_{C}=0$			100	nA
h _{FE1}	* DC Current Gain	V _{CE} =1V, I _C =100mA	120	200	400	
h_{FE2}		V _{CE} =1V, I _C =700mA	35	140		
V _{BE} (on)	Base-Emitter On Voltage	V _{CE} =6V, I _C =10mA	600	640	700	mV
V _{CE} (sat)	Collector-Emitter Saturation Voltage	I _C =700mA, I _B =70mA		0.2	0.4	V
V _{BE} (sat)	Base-Emitter Saturation Voltage	I _C =700mA, I _B =70mA		0.95	1.2	V
C _{ob}	Output Capacitance	V _{CB} =6V, I _E =0, f=1MHz		13	25	pF
f _T	Current Gain Bandwidth Product	V _{CE} =6V, I _C =10mA	50	170		MHz
f _T	' '		50	170		MH

^{*} Pulse Test: PW≤350μs, Duty Cycle≤ 2%

h_{FE1} Classification

Classification	Y	G
h _{FE1}	120 ~ 240	200 ~ 400

Typical Characteristics

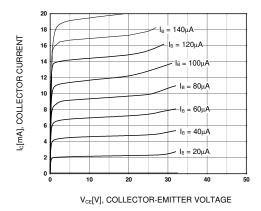


Figure 1. Static Characteristic

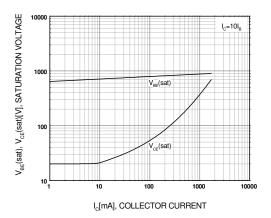


Figure 3. Base-Emitter Saturation Voltage Collector-Emitter Saturation Voltage

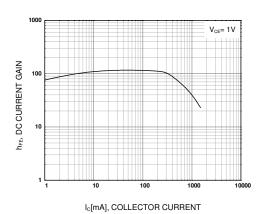


Figure 2. DC current Gain

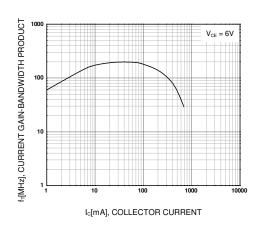
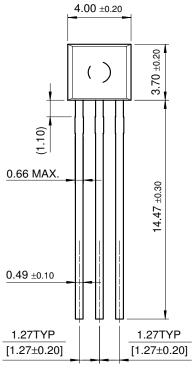


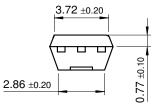
Figure 4. Current Gain-Bandwidth Product

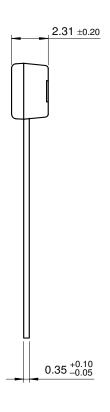
KSD1020

Package Dimensions

TO-92S







Dimensions in Millimeters

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